

TOSHIBA Field-Effect Transistor Silicon N-Channel MOS Type

SSM3K309T

- Power Management Switch Applications
- High-Current Switching Applications

- 1.8V drive
- Low on-resistance : $R_{ON} = 47\text{m}\Omega$ (max.) (@ $V_{GS} = 1.8\text{V}$)
 : $R_{ON} = 35\text{m}\Omega$ (max.) (@ $V_{GS} = 2.5\text{V}$)
 : $R_{ON} = 31\text{m}\Omega$ (max.) (@ $V_{GS} = 4.0\text{V}$)

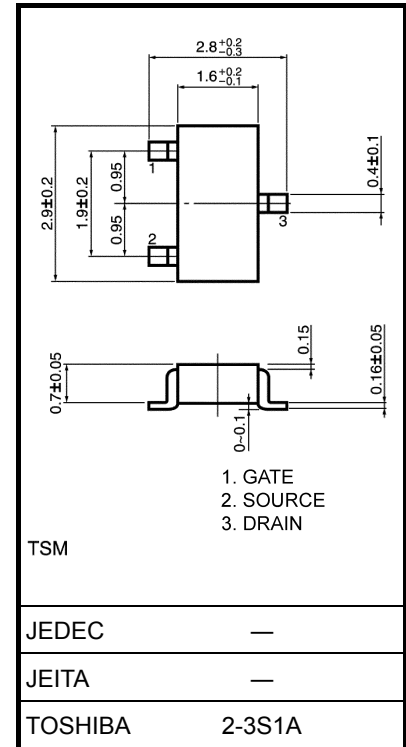
Absolute Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Drain-source voltage	V_{DS}	20	V
Gate-source voltage	V_{GSS}	± 12	V
Drain current	DC	I_D	4.7
	Pulse	I_{DP}	9.4
Drain power dissipation	P_D (Note 1)	700	mW
Channel temperature	T_{ch}	150	°C
Storage temperature range	T_{stg}	-55~150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.
 Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Mounted on an FR4 board.
 (25.4 mm × 25.4 mm × 1.6 t, Cu Pad: 645 mm²)

Unit: mm



Weight: 10mg (typ.)

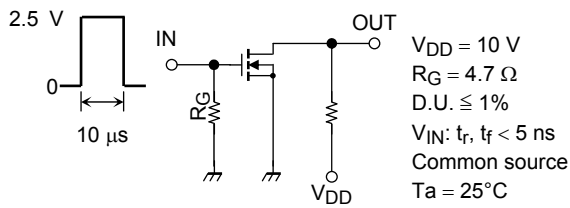
Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit	
Drain-source breakdown voltage	$V_{(BR)DSS}$	$I_D = 1\text{ mA}, V_{GS} = 0$	20	—	—	V	
	$V_{(BR)DSX}$	$I_D = 1\text{ mA}, V_{GS} = -12\text{ V}$	12	—	—	V	
Drain cutoff current	I_{DSS}	$V_{DS} = 20\text{ V}, V_{GS} = 0$	—	—	1	μA	
Gate leakage current	I_{GSS}	$V_{GS} = \pm 12\text{ V}, V_{DS} = 0$	—	—	±1	μA	
Gate threshold voltage	V_{th}	$V_{DS} = 3\text{ V}, I_D = 1\text{ mA}$	0.35	—	1.0	V	
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = 3\text{ V}, I_D = 4.0\text{ A}$ (Note2)	13	25	—	S	
Drain-source ON-resistance	$R_{DS(ON)}$	$I_D = 4.0\text{ A}, V_{GS} = 4.0\text{ V}$ (Note2)	—	22	31	mΩ	
		$I_D = 3.0\text{ A}, V_{GS} = 2.5\text{ V}$ (Note2)	—	25	35		
		$I_D = 1.0\text{ A}, V_{GS} = 1.8\text{ V}$ (Note2)	—	30	47		
Input capacitance	C_{iss}	$V_{DS} = 10\text{ V}, V_{GS} = 0, f = 1\text{ MHz}$	—	1020	—	pF	
Output capacitance	C_{oss}	$V_{DS} = 10\text{ V}, V_{GS} = 0, f = 1\text{ MHz}$	—	175	—	pF	
Reverse transfer capacitance	C_{rss}	$V_{DS} = 10\text{ V}, V_{GS} = 0, f = 1\text{ MHz}$	—	160	—	pF	
Switching time	Turn-on time	t_{on}	$V_{DD} = 10\text{ V}, I_D = 2\text{ A}$	—	23	—	ns
	Turn-off time	t_{off}	$V_{GS} = 0\sim 2.5\text{ V}, R_G = 4.7\ \Omega$	—	34	—	
Drain-source forward voltage	V_{DSF}	$I_D = -4.7\text{ A}, V_{GS} = 0$ (Note2)	—	-0.85	-1.2	V	

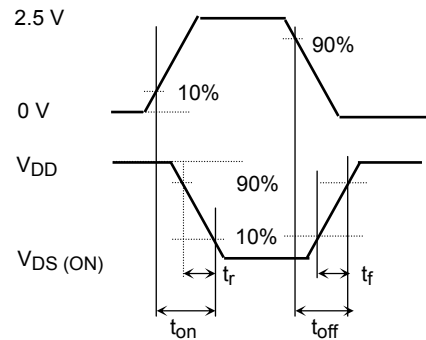
Note2: Pulse test

Switching Time Test Circuit

(a) Test Circuit

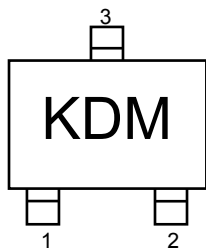


(b) V_{IN}

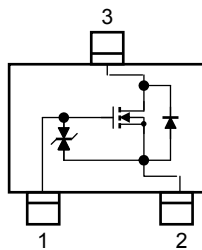


(c) V_{OUT}

Marking



Equivalent Circuit (top view)



Precaution

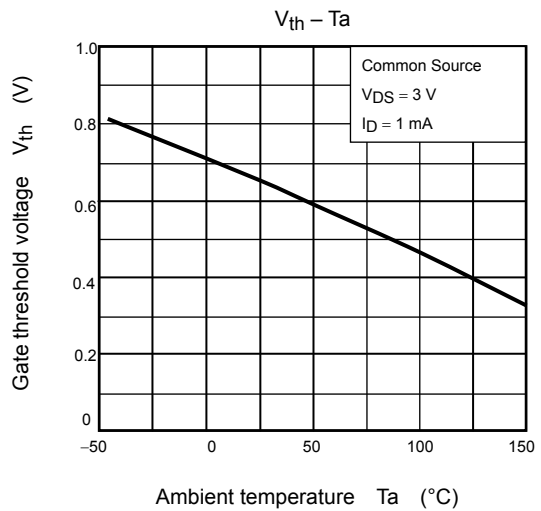
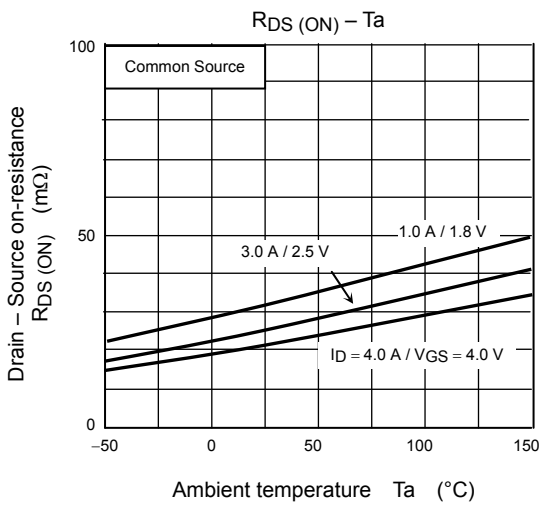
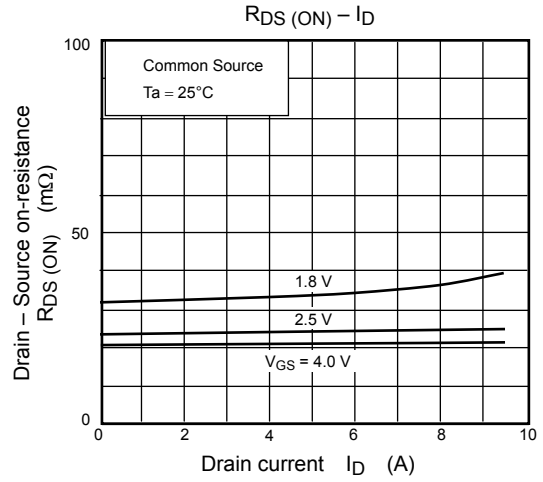
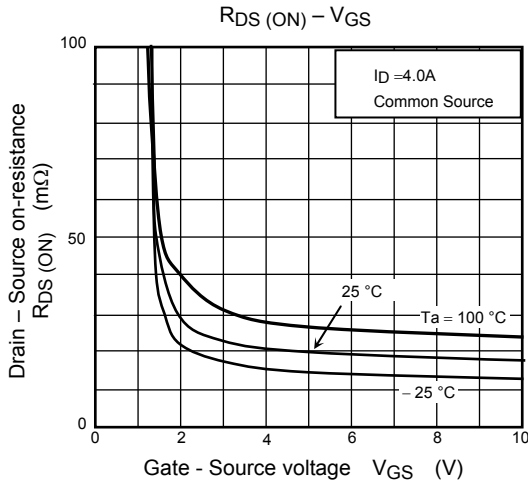
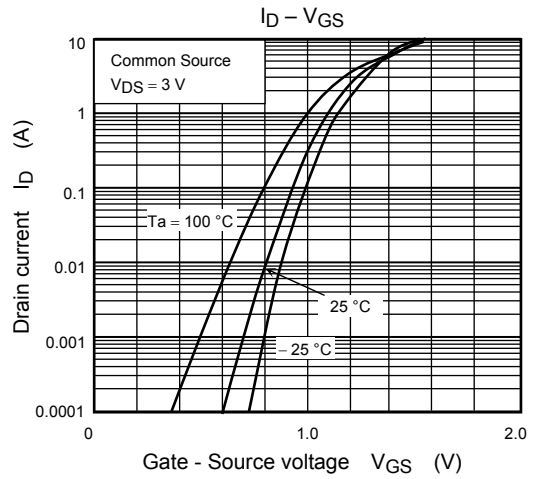
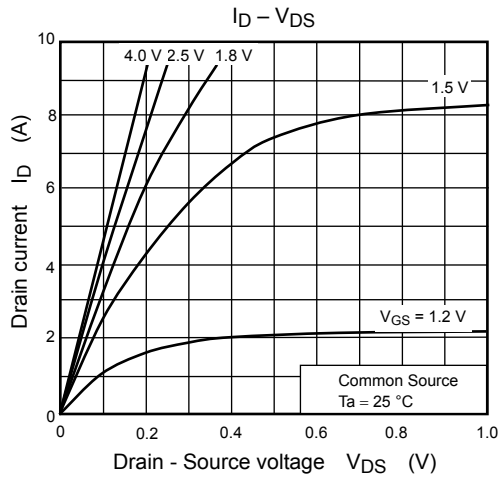
V_{th} can be expressed as the voltage between gate and source when the low operating current value is $I_D = 1 \text{ mA}$ for this product. For normal switching operation, $V_{GS(ON)}$ requires a higher voltage than V_{th} and $V_{GS(OFF)}$ requires a lower voltage than V_{th} .

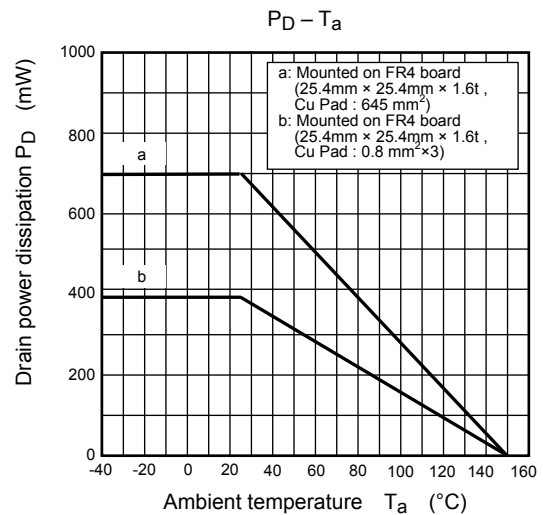
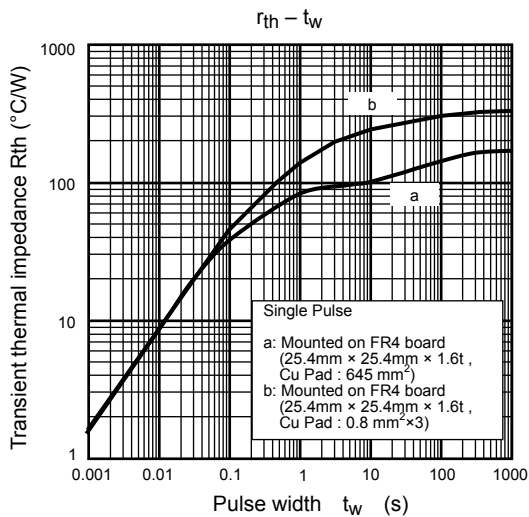
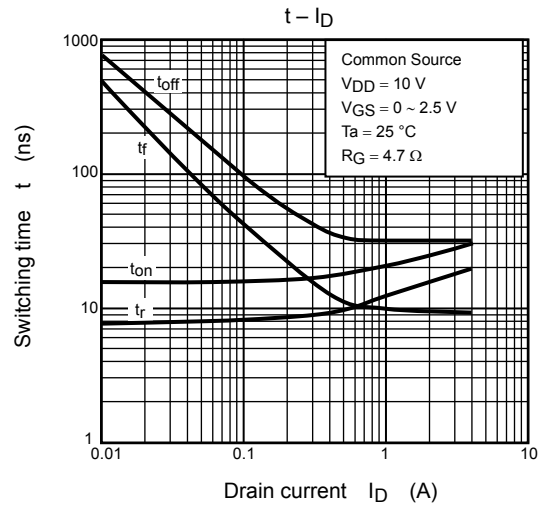
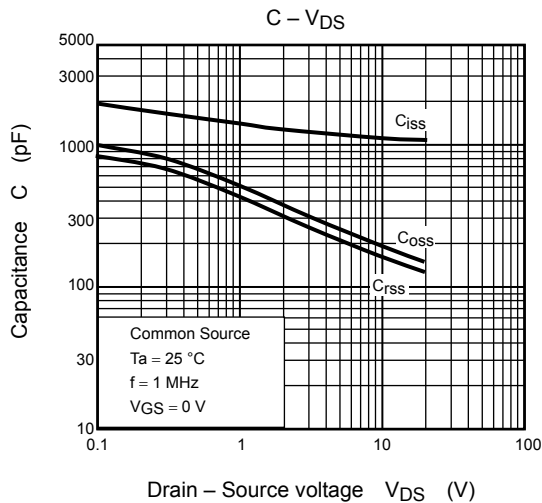
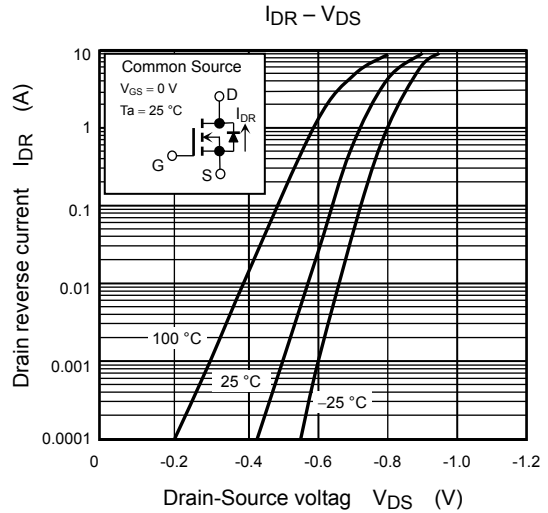
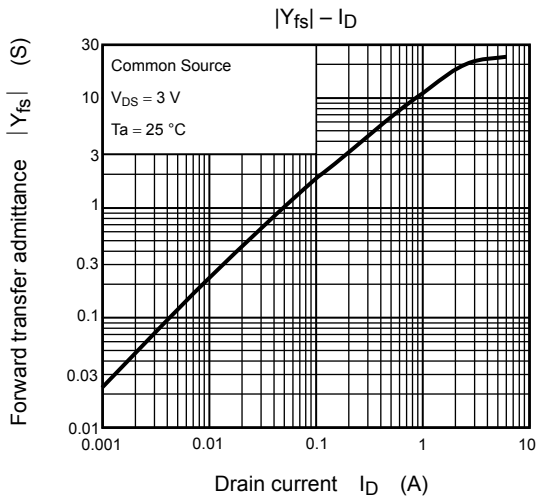
(The relationship can be established as follows: $V_{GS(OFF)} < V_{th} < V_{GS(ON)}$.)

Take this into consideration when using the device.

Handling Precaution

When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.





RESTRICTIONS ON PRODUCT USE

20070701-EN GENERAL

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- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc.
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